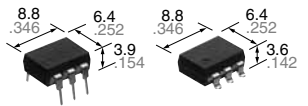


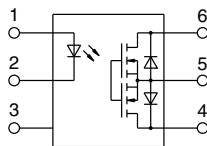
6-pin type for switching low-level analog signal

PhotoMOS[®] GU 1 Form A (AQV210, AQV214H)



(Height includes standoff)

mm inch



RoHS compliant

FEATURES

- Controls low-level analog signals**
PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- Controls various types of loads such as relays, motors, lamps and solenoids**
- Optical coupling for extremely high isolation**
Unlike mechanical relays, the PhotoMOS combines LED and optoelectronic device to transfer signals using light for extremely high isolation.
- Eliminates the need for a counter electromotive force protection diode in the drive circuits on the input side**

- Stable on-resistance**
- Low-level off state leakage current of max. 1 μA**
- Reinforced insulation type of I/O voltage 5,000Vrms also available**

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Data communication equipment
- Computers

TYPES

	I/O isolation	Output rating*		Package	Part No.				Packing quantity	
					Through hole terminal	Surface-mount terminal			Tube	Tape and reel
						Tube packing style		Tape and reel packing style		
		Load voltage	Load current			Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side			
AC/DC dual use	Standard 1,500 Vrms	60 V	550 mA	DIP6-pin	AQV212	AQV212A	AQV212AX	AQV212AZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.
		100 V	320 mA		AQV215	AQV215A	AQV215AX	AQV215AZ		
		200 V	180 mA		AQV217	AQV217A	AQV217AX	AQV217AZ		
		350 V	130 mA		AQV210	AQV210A	AQV210AX	AQV210AZ		
		400 V	120 mA		AQV214	AQV214A	AQV214AX	AQV214AZ		
	600 V	50 mA	AQV216		AQV216A	AQV216AX	AQV216AZ			
	Reinforced 5,000 Vrms	400 V	120 mA		AQV214H	AQV214HA	AQV214HAX	AQV214HAZ		

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

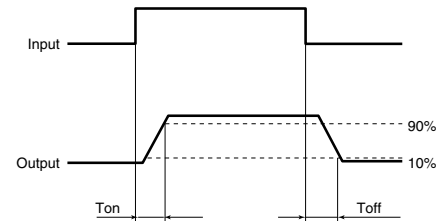
Item	Sym- bol	Type of connec- tion	AQV212(A)	AQV215(A)	AQV217(A)	AQV210(A)	AQV214(A)	AQV216(A)	AQV214H(A)	Remarks	
Input	LED forward current	I _F	50 mA								
	LED reverse voltage	V _R	5 V								
	Peak forward current	I _{FP}	1 A							f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	P _{in}	75 mW								
Load voltage (peak AC)	V _L		60 V	100 V	200 V	350 V	400 V	600 V	400 V		
Output	Continuous load current	A	0.55 A	0.32 A	0.18 A	0.13 A	0.12 A	0.05 A	0.12 A	A connection: Peak AC, DC B, C connection: DC	
		B	0.65 A	0.42 A	0.22 A	0.15 A	0.13 A	0.06 A	0.13 A		
		C	0.80 A	0.60 A	0.30 A	0.17 A	0.15 A	0.08 A	0.15 A		
Peak load current	I _{peak}		1.5 A	0.96 A	0.54 A	0.4 A	0.3 A	0.15 A	0.3 A	A connection: 100 ms (1 shot), V _L =DC	
Power dissipation	P _{out}		500 mW								
Total power dissipation	P _T		550 mW								
I/O isolation voltage	V _{iso}		1,500 Vrms							5,000 Vrms	
Ambient temperature	Operating	T _{opr}	-40 to +85°C -40 to +185°F								(Non-icing at low temperatures)
	Storage	T _{stg}	-40 to +100°C -40 to +212°F								

GU 1 Form A (AQV210, AQV214H)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection**	AQV212(A)	AQV215(A)	AQV217(A)	AQV210(A)	AQV214(A)	AQV216(A)	AQV214H(A)	Condition	
Input	LED operate current	Typical	—	1 mA						1.3 mA	I _L = Max.	
		Maximum		3 mA								
	LED turn off current	Minimum	—	0.4 mA						1.2 mA	I _L = Max.	
		Typical		0.79 mA								
LED dropout voltage	Typical	V _F	—	1.25 V (1.14 V at I _F = 5 mA)						I _F = 50 mA		
	Maximum			1.5 V								
Output	On resistance	Typical	R _{on}	A	0.83 Ω	2.3 Ω	11.0 Ω	23 Ω	30 Ω	70 Ω	30 Ω	I _F = 5 mA I _L = Max. Within 1 s
		Maximum	R _{on}	A	2.5 Ω	4.0 Ω	15.0 Ω	35 Ω	50 Ω	120 Ω	50 Ω	I _F = 5 mA I _L = Max. Within 1 s
	Typical	R _{on}	B	0.44 Ω	1.15 Ω	5.5 Ω	11.5 Ω	22.5 Ω	55 Ω	22.5 Ω	I _F = 5 mA I _L = Max. Within 1 s	
	Maximum	R _{on}	B	1.25 Ω	2.0 Ω	7.5 Ω	17.5 Ω	25 Ω	100 Ω	25 Ω	I _F = 5 mA I _L = Max. Within 1 s	
	Typical	R _{on}	C	0.25 Ω	0.6 Ω	2.8 Ω	6.0 Ω	11.3 Ω	28 Ω	11.3 Ω	I _F = 5 mA I _L = Max. Within 1 s	
	Maximum	R _{on}	C	0.63 Ω	1.0 Ω	3.8 Ω	8.8 Ω	12.5 Ω	50 Ω	12.5 Ω	I _F = 5 mA I _L = Max. Within 1 s	
Off state leakage current	Maximum	I _{Leak}	—	1 μA						I _F = 0 mA V _L = Max.		
Transfer characteristics	Turn on time*	Typical	T _{on}	—	0.65 ms	0.6 ms	0.25 ms	0.21 ms	0.28 ms	0.6 ms	I _F = 5 mA I _L = Max.	
		Maximum			2 ms		1.0 ms	0.5 ms		0.8 ms		
	Turn off time*	Typical	T _{off}	—	0.08 ms	0.06 ms	0.05 ms		0.04 ms	0.05 ms	I _F = 5 mA I _L = Max.	
		Maximum			0.2 ms							
	I/O capacitance	Typical	C _{iso}	—	0.8 pF						f = 1 MHz V _S = 0 V	
Maximum		1.5 pF										
Initial I/O isolation resistance	Minimum	R _{iso}	—	1,000 MΩ						500 V DC		

*Turn on/Turn off time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

Item		Symbol	Min.	Max.	Unit
LED current		I _F	5	30	mA
AQV212(A)	Load voltage (Peak AC)	V _L	—	48	V
	Continuous load current (A connection)	I _L	—	0.5	A
AQV215(A)	Load voltage (Peak AC)	V _L	—	80	V
	Continuous load current (A connection)	I _L	—	0.3	A
AQV217(A)	Load voltage (Peak AC)	V _L	—	160	V
	Continuous load current (A connection)	I _L	—	0.18	A
AQV210(A)	Load voltage (Peak AC)	V _L	—	280	V
	Continuous load current (A connection)	I _L	—	0.13	A
AQV214(A)	Load voltage (Peak AC)	V _L	—	320	V
	Continuous load current (A connection)	I _L	—	0.12	A
AQV216(A)	Load voltage (Peak AC)	V _L	—	480	V
	Continuous load current (A connection)	I _L	—	0.05	A
AQV214H(A)	Load voltage (Peak AC)	V _L	—	320	V
	Continuous load current (A connection)	I _L	—	0.12	A

■ These products are not designed for automotive use.

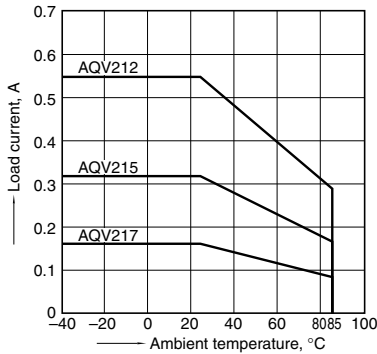
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C
-40 to +185°F

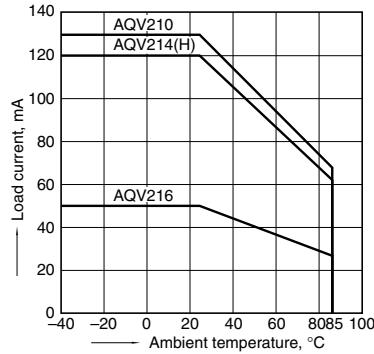
Type of connection: A



1-(2). Load current vs. ambient temperature characteristics

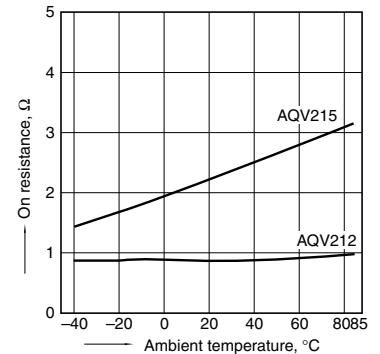
Allowable ambient temperature: -40 to +85°C
-40 to +185°F

Type of connection: A



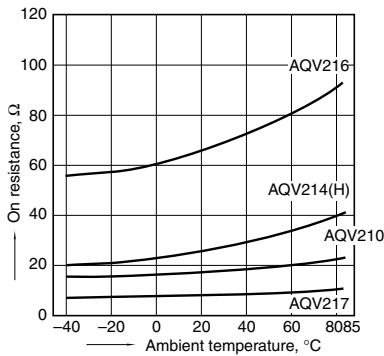
2-(1). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Load voltage: Max. (DC)
Continuous load current: Max. (DC)



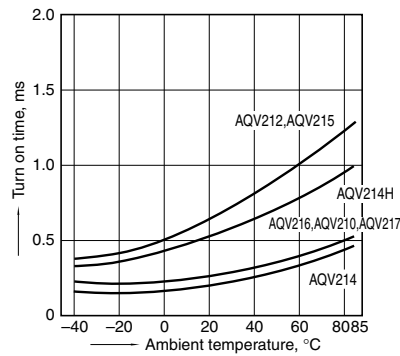
2-(2). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Load voltage: Max. (DC)
Continuous load current: Max. (DC)



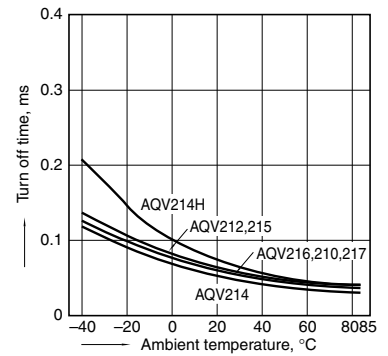
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



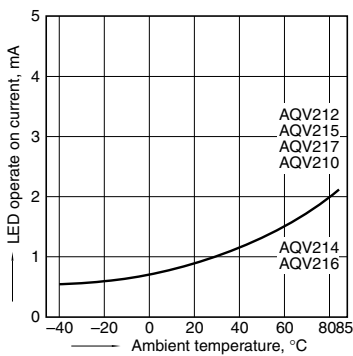
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



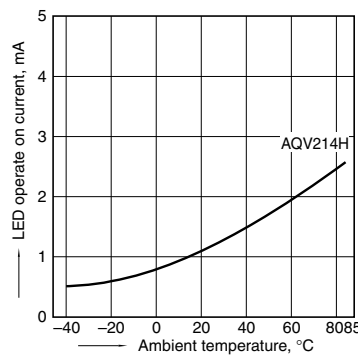
5-(1). LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



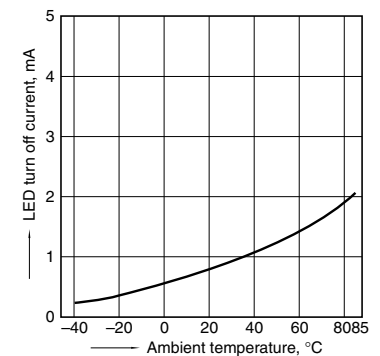
5-(2). LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



6-(1). LED turn off current vs. ambient temperature characteristics

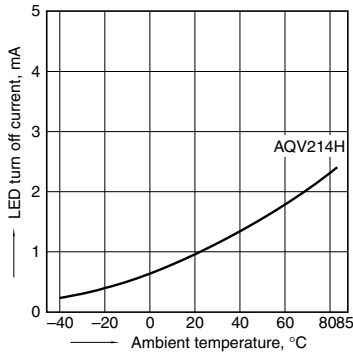
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



GU 1 Form A (AQV210, AQV214H)

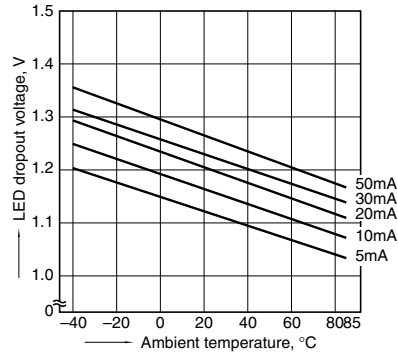
6-(2). LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



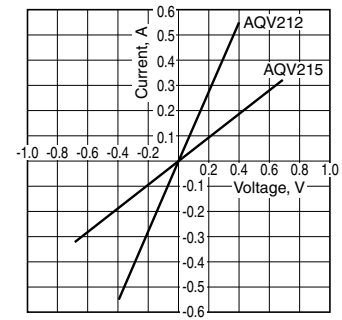
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types
LED current: 5 to 50 mA



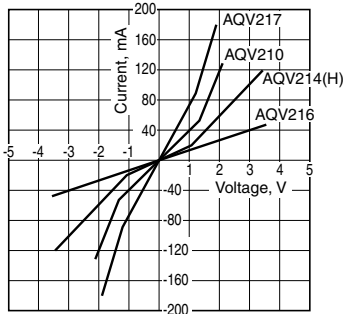
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



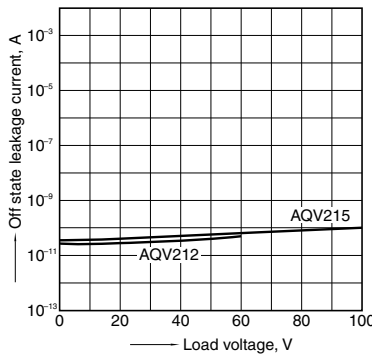
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



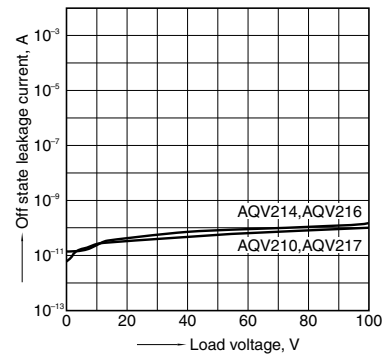
9-(1). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



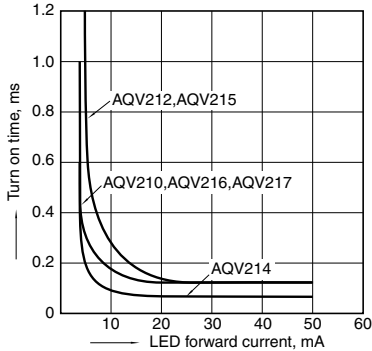
9-(2). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



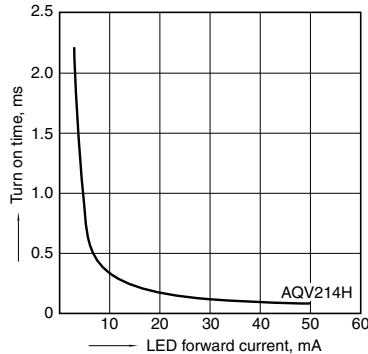
10-(1). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



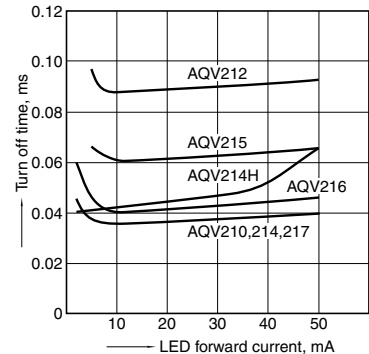
10-(2). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



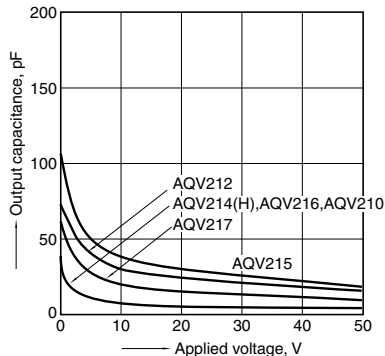
11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F



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